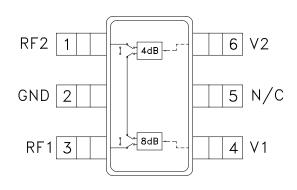


Typical Applications

The HMC291 is ideal for:

- Cellular
- PCS, ISM, MMDS
- WLL Handset & Base Station

Functional Diagram



Features

4 dB LSB Steps to 12 dB

Single Positive Control Per BIT, 0/+3V

+/-0.2 dB Typical Bit Error

Miniature SOT 26 Package: 9 mm²

General Description

The HMC291 is a broadband 2 - bit positive control GaAs IC digital attenuator in a 6 lead SOT26 surface mount plastic package. Covering 0.7 to 4 GHz, the insertion loss is typically less than 0.7 to 1.3 dB. The attenuator bit values are 4 (LSB) and 8 dB for a total attenuation of 12 dB. Accuracy is excellent at \pm 0.2 dB typical with an IIP3 of up to +54 dBm. Two bit control voltage inputs, toggled between 0 and +3 to +5 volts, are used to select each attenuation state at less than 50 uA each. A single Vdd bias of +3 to +5 volts applied through an external 5K Ohm resistor is required.

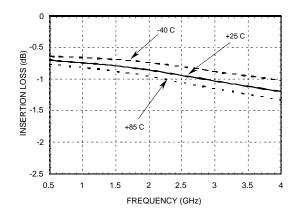
Electrical Specifications,

 $T_{\Delta} = +25^{\circ}$ C, Vdd = +3V to +5V & Vctl = 0/Vdd (Unless Otherwise Stated)

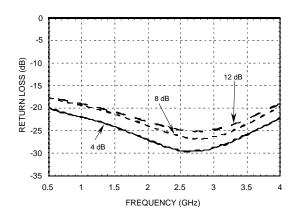
| Parameter | | Frequency | Min. | Typical | Max. | Units |
|--|----|---------------|------------|-----------------|-----------|-------|
| Insertion Loss | | 0.7 - 1.4 GHz | | 0.7 | 1.0 | dB |
| | | 1.4 - 2.3 GHz | | 0.9 | 1.3 | dB |
| | | 2.3 - 2.7 GHz | | 1.0 | 1.4 | dB |
| | | 2.7 - 4.0 GHz | | 1.1 | 1.6 | dB |
| Attenuation Range | | 0.7 - 4.0 GHz | | 12 | | dB |
| Return Loss (RF1 & RF2, All Atten. States) | | 0.7 - 1.4 GHz | 14 | 17 | | dB |
| • | | 1.4 - 4.0 GHz | 16 | 22 | | dB |
| Attenuation Accuracy: (Referenced to Insertion Loss) | | | | | | |
| All Attenuation States | | 0.7 - 1.4 GHz | ± 0.3 + 3° | % of Atten. Se | tting Max | dB |
| All Attenuation States | | 1.4 - 2.3 GHz | ± 0.2 + 2 | % of Atten. Se | tting Max | dB |
| All Attenuation States | | 2.3 - 2.7 GHz | ± 0.2 + 3° | % of Atten. Set | tting Max | dB |
| All Attenuation States | | 2.7 - 4.0 GHz | ± 0.4 + 5 | % of Atten. Se | tting Max | dB |
| Input Power for 0.1 dB Compression | 5V | 0.7 - 4.0 GHz | | 26 | | dBm |
| · | 3V | | | 22 | | dBm |
| Input Third Order Intercept Point | 5V | 0.7 - 4.0 GHz | | 54 | | dBm |
| (Two-tone Input Power = 0 dBm Each Tone) | 3V | | | 50 | | dBm |
| Switching Characteristics | | 0.7 - 4.0 GHz | | | | |
| tRISE, tFALL (10/90% RF) | | | | 560 | | ns |
| tON, tOFF (50% CTL to 10/90% RF) | | | | 600 | | ns |



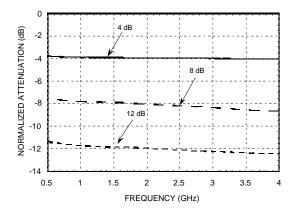
Insertion Loss



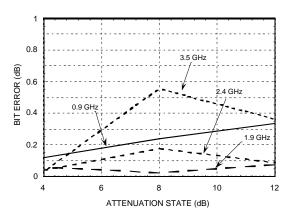
Return Loss RF1, RF2



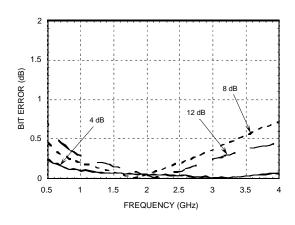
Normalized Attenuation



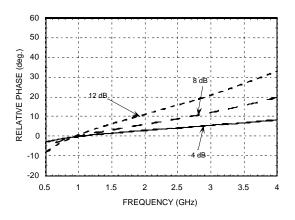
Absolute Bit Error vs. Attenuation State



Absolute Bit Error vs. Frequency



Relative Phase vs. Frequency



Note: All Data Typical Over Voltage (+3V to +5V) & Temperature (-40 to +85 deg. C.).



Truth Table

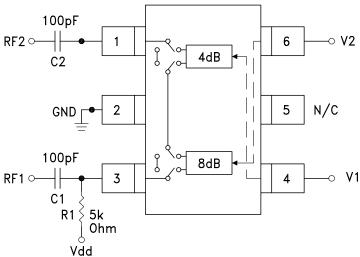
| Control Voltage Input | | Attenuation | |
|-----------------------|------------|----------------------|--|
| V1 8 dB | V2 4 dB | Setting RF1 - RF2 | |
| High | High | Reference I.L. | |
| High | Low | 4 dB | |
| Low | High | 8 dB | |
| Low | Low | 12 dB Max. Atten. | |
| Low | Low | 12 dB | |

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

Control & Bias Voltages

| State | Bias Condition | |
|------------------------------------|-------------------------|--|
| Low | 0 to +0.2V @ 20 uA Max. | |
| High | Vdd ± 0.2V @ 50 uA Max. | |
| Note: $Vdd = +3V$ to $5V \pm 0.2V$ | | |

Application Circuit



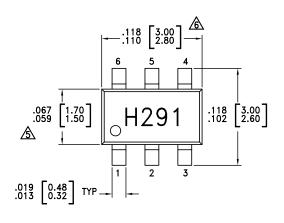
DC blocking capacitors C1 & C2 are required on RF1 & RF2. Choose C1 = $C2 = 100 \sim 300$ pF to allow lowest customer specific frequency to pass with minimal loss. R1 = 5K Ohm is required to supply voltage to the circuit throught either PIN 3 or PIN 1.

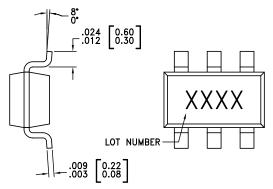


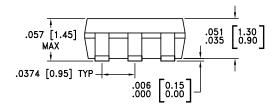
Absolute Maximum Ratings

| Control Voltage (V1, V2) | Vdd + 0.5 Vdc |
|------------------------------|----------------|
| Bias Voltage (Vdd) | +8.0 Vdc |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |
| RF Input Power (0.7 - 4 GHz) | +28 dBm |

Outline Drawing





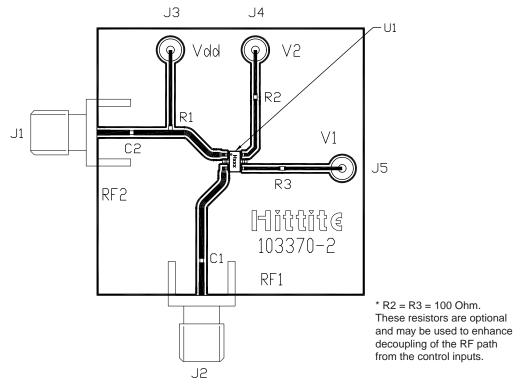


NOTES:

- PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEADFRAME MATERIAL: COPPER ALLOY
- 3. LEADFRAME PLATING: Sn/Pb SOLDER
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- 6 DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.



Evaluation Circuit Board



The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation circuit board as shown is available from Hittite Microwave Corporation upon request.

List of Material

| Item | Description | |
|-------------------------------------|---|--|
| J1 - J2 | PC Mount SMA Connector | |
| J3 - J6 | DC Pin | |
| R1 | 5k Ohm Resistor, 0402 Chip | |
| R2, R3 | 100 Ohm Resistor, 0402 Chip | |
| C1, C2 | 0402 Chip Capacitor, Select for Lowest Frequency of Operation | |
| U1 | HMC291 Digital Attenuator | |
| PCB* | 103370 Evaluation PCB 1.5" x 1.5" | |
| *Circuit Board Material Rogers 4350 | | |



Notes: